



	IAB110P	Units
Load Voltage	350	V
Load Current	100	mA
Max R _{ON}	35	Ω

Features

- Three Functions in One Package
- Small 16 Pin SOIC Package (PCMCIA Compatible)
- Bi-Directional Current Sensing
- Bi-Directional Current Switching
- 3750V_{RMS} Input/Output Isolation
- FCC Compatible
- No EMI/RFI Generation
- Machine Insertable, Wave Solderable
- Tape & Reel Versions Available

Applications

- Telecommunications
 - Telecom Switching
 - Tip/Ring Circuits
 - Modem Switching (Laptop, Notebook, Pocket Size)
 - Hookswitch
 - Dial Pulsing
 - Ground Start
 - Ringer Injection
- Instrumentation
 - Multiplexers
 - Data Acquisition
 - Electronic Switching
 - I/O Subsystems
 - Meters (Watt-Hour, Water, Gas)
- Medical Equipment-Patient/Equipment Isolation
- Security
- Aerospace
- Industrial Controls

Description

The IAB110P Multifunction Telecom switch combines a 350V Form A relay, 350V Form B relay and one optocoupler in a single package. The relay uses optically coupled MOSFET technology to provide 1500V of input to output isolation. The efficient MOSFET switches and photovoltaic die use Clare's patented OptoMOS architecture. The optically coupled input uses highly efficient GaAlAs infrared LEDs. IAB110P's allow telecom circuit designers to combine three discrete functions in a single component. The IAB110P's small package uses less space than traditional discrete component solutions.

Approvals

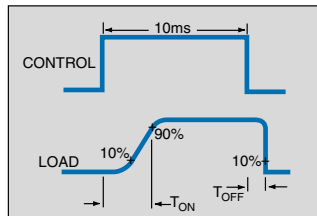
- UL Recognized: File Number E76270
- CSA Certified: File Number LR 43639-12
- VDE Compatible
- BSI Certified:
 - BS EN 60950:1992 (BS7002:1992) Certificate #:7969
 - BS EN 41003:1993 Certificate #:7969

Ordering Information

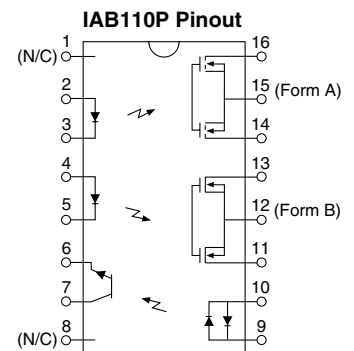
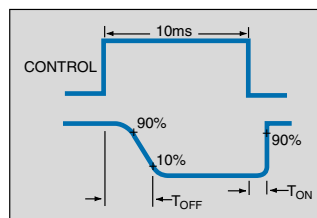
Part #	Description
IAB110P	16 Pin SOIC (50/Tube)
IAB110PTR	16 Pin SOIC (1000/Reel)

Pin Configuration

Switching Characteristics of Normally Open (Form A) Devices



Switching Characteristics of Normally Closed (Form B) Devices



1. (N/C)
2. + LED - Form A Relay #1
3. - LED - Form A Relay #1
4. + LED - Form B Relay #2
5. - LED - Form B Relay #2
6. Emitter - Phototransistor
7. Collector - Phototransistor
8. (N/C)
9. LED - Phototransistor +/-
10. LED - Phototransistor -/+
11. Output - Form B Relay #2
12. Common Source Relay #2
13. Output - Form B Relay #2
14. Output - Form A Relay #1
15. Common Source Relay #1
16. Output - Form A Relay #1

Absolute Maximum Ratings (@ 25° C)

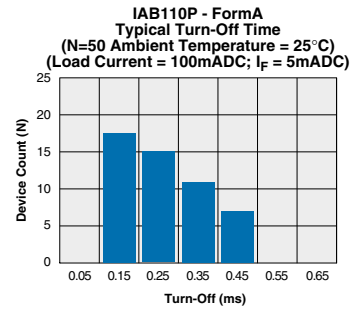
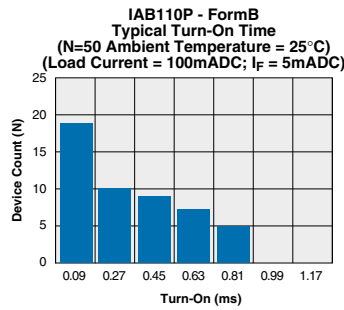
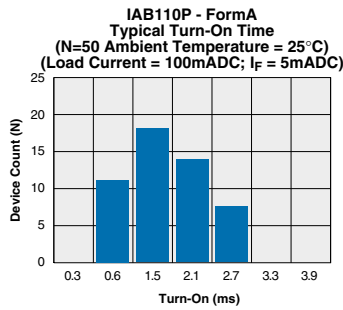
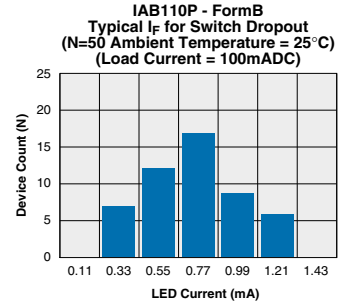
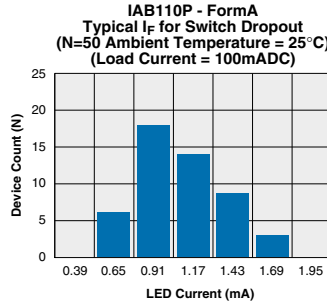
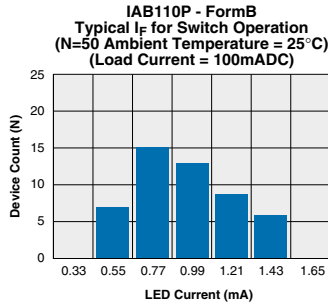
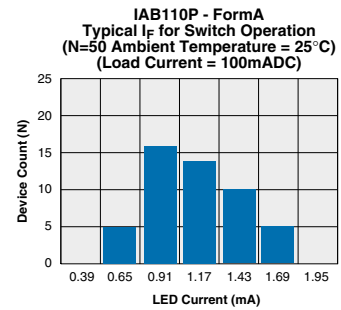
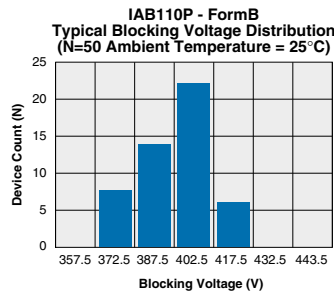
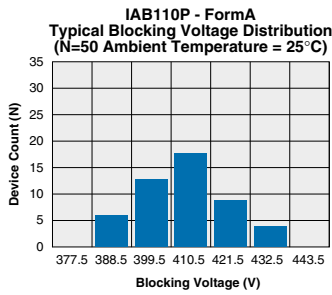
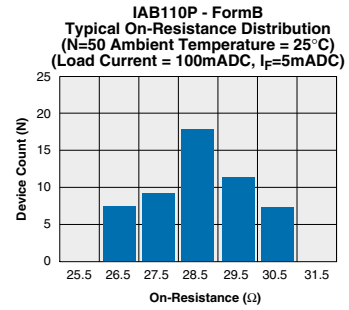
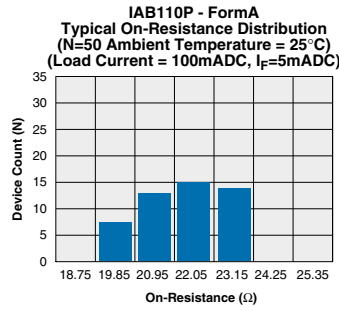
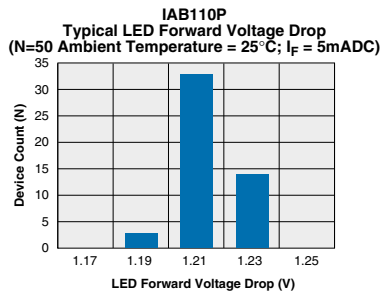
Parameter	Min	Typ	Max	Units
Total Package Dissipation	-	-	1 ¹	W
Isolation Voltage Input to Output	3750	-	-	V _{RMS}
Operational Temperature	-40	-	+85	°C
Storage Temperature	-40	-	+125	°C
Soldering Temperature (10 Seconds Max.)	-	-	+220	°C

¹ Above 25° derate linearly 1.67mw/°C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and effect its reliability.

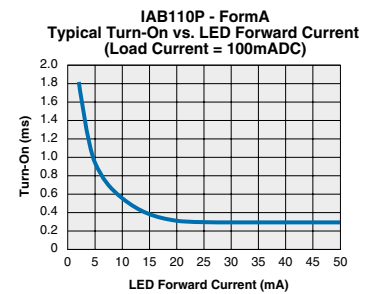
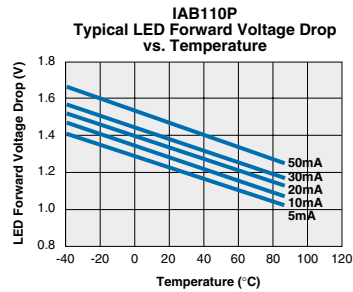
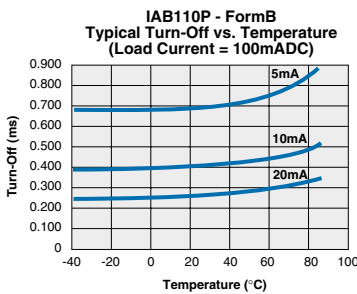
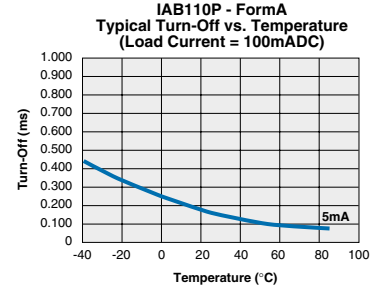
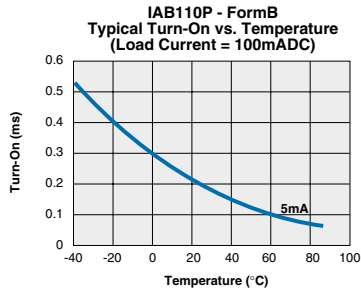
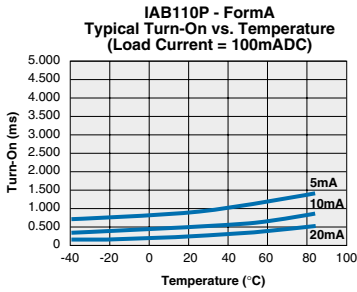
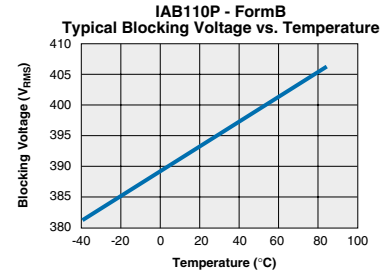
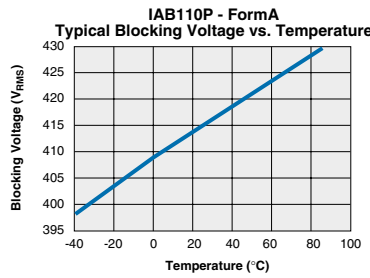
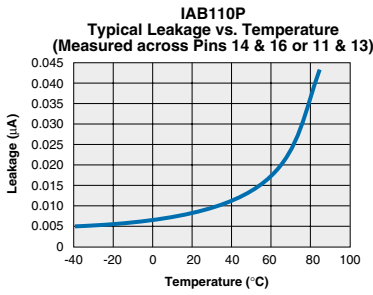
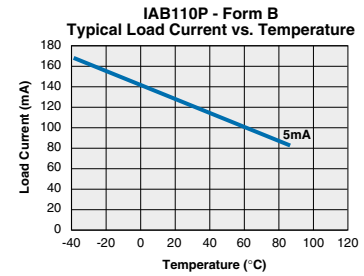
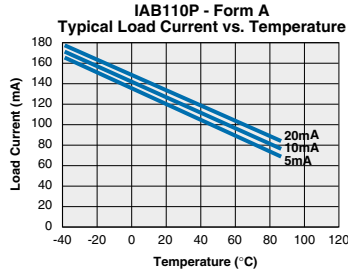
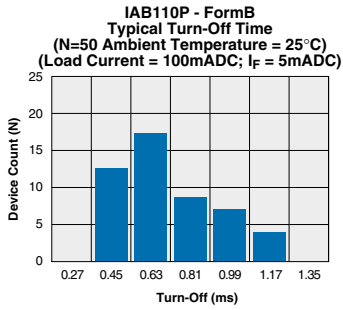
Electrical Characteristics

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Relay Portion						
Output Characteristics @ 25°C						
Load Voltage (Peak)	I _L = 1μA	V _L	-	-	350	V
Load Current (Continuous)	-	I _L	-	-	100	mA
Peak Load Current	10ms	I _{LPK}	-	-	350	mA
On-Resistance	I _L = 100mA	R _{ON}	-	-	35	Ω
Off-State Leakage Current	V _L = 350V; T _J = 25°C	I _{LEAK}	-	-	1	μA
Switching Speeds						
Turn-On	I _F = 5mA, V _L = 10V	T _{ON}	-	-	3	ms
Turn-Off	I _F = 5mA, V _L = 10V	T _{OFF}	-	-	3	ms
Output Capacitance	V _L = 50V, f = 1MHz	-	-	25	-	pF
Relay Portion						
Input Characteristics @ 25°C						
Input Control Current	I _L = 100mA	I _F	5	-	50	mA
Input Dropout Current	I _L = 1mA	I _F	0.4	-	-	mA
Input Voltage Drop	I _F = 5mA	V _F	0.9	1.2	1.4	V
Reverse Input Voltage	-	V _R	-	-	5	V
Reverse Input Current	V _R = 5V	I _R	-	-	10	μA
Detector Portion						
Output Characteristics @ 25°C						
Phototransistor Blocking Voltage	I _C = 10μA	BV _{CEO}	20	50	-	V
Phototransistor Dark Current	V _{CE} = 5V, I _F = 0mA	I _{CEO}	-	50	500	nA
Saturation Voltage	I _C = 2mA, I _F = 16mA	V _{SAT}	-	0.3	0.5	V
Current Transfer Ratio	I _F = 6mA, V _{CE} = 0.5V	C _{TR}	33	-	-	%
Detector Portion						
Input Characteristics @ 25°C						
Input Control Current	I _C = 2mA, V _{CE} = 0.5V	I _F	6	2	-	mA
Input Voltage Drop	I _F = 5mA	I _{CEO}	0.9	1.2	1.4	V
Input Current (Detector must be off)	I _C = 1μA, V _{CE} = 5V	-	5	25	-	μA
Input to Output Capacitance	V _L = 50V, f = 1MHz	C _{I/O}	-	3	-	pF
Input to Output Isolation	-	V _{I/O}	3750	-	-	V _{RMS}

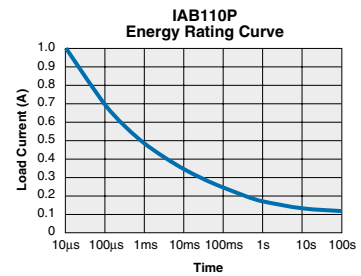
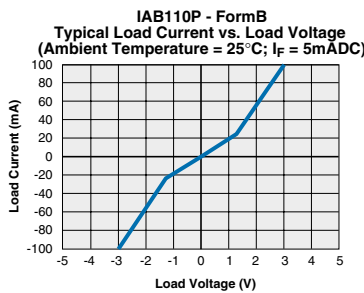
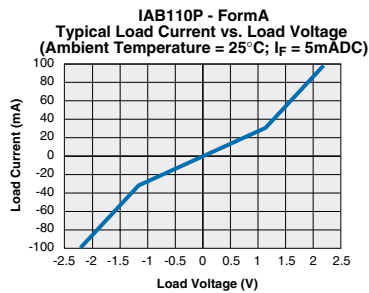
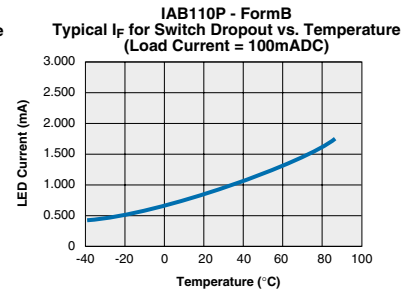
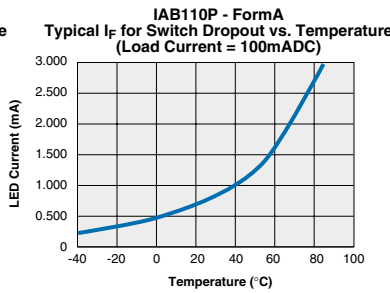
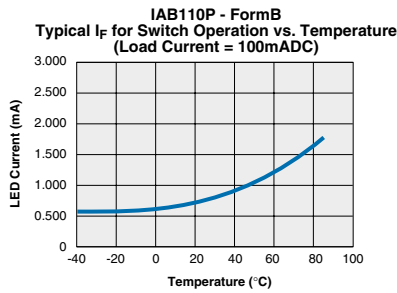
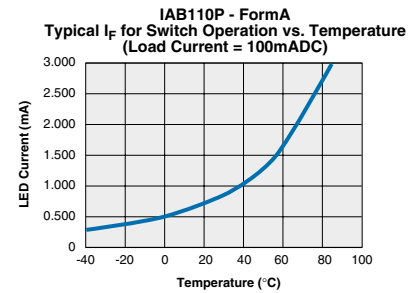
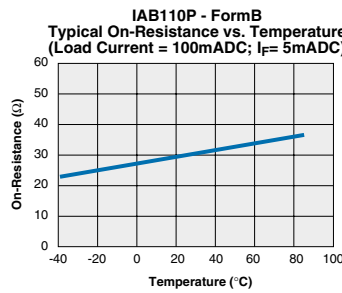
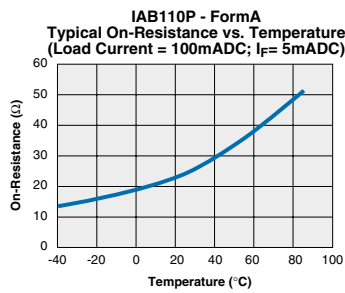
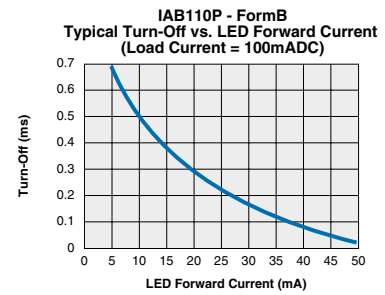
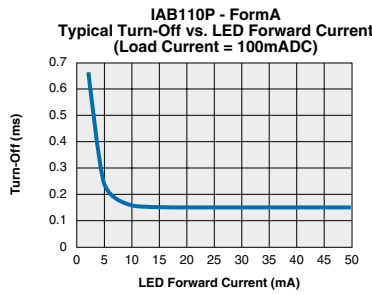
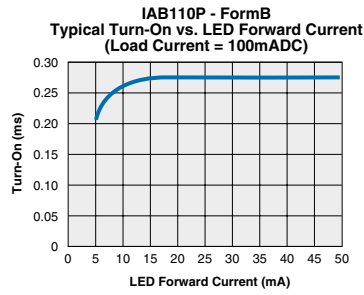
PERFORMANCE DATA*


The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

PERFORMANCE DATA*

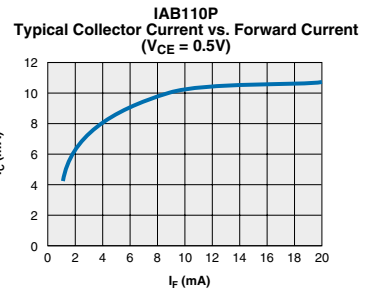
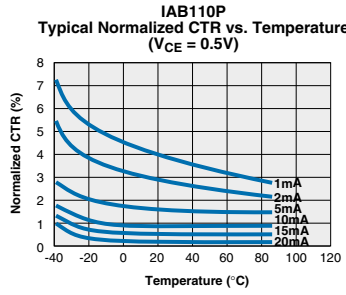
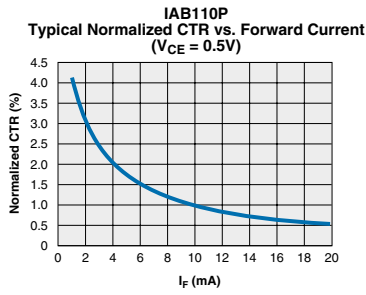


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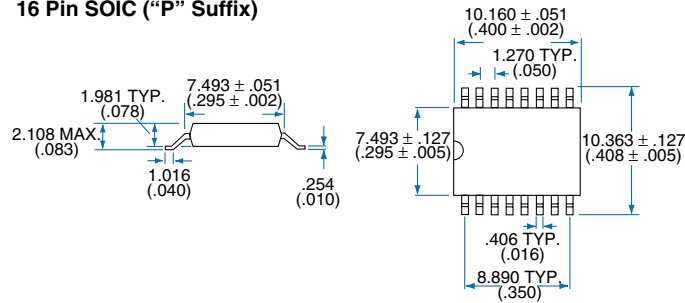
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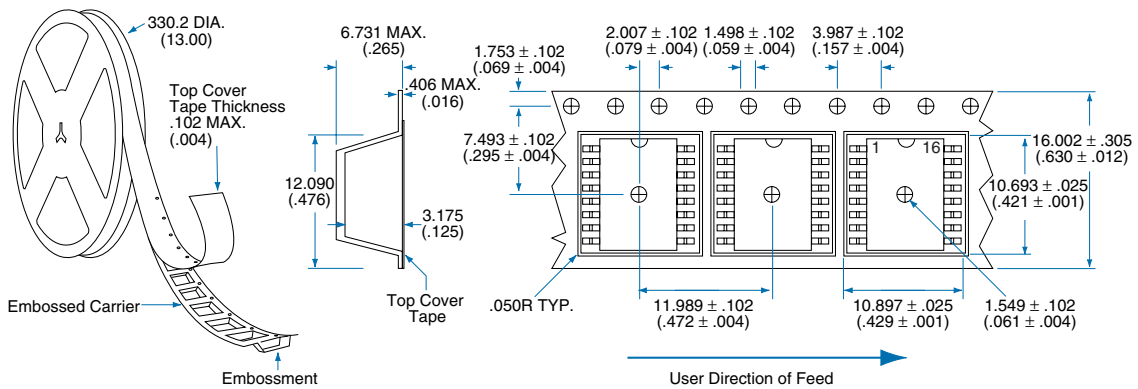


Mechanical Dimensions

16 Pin SOIC ("P" Suffix)



Tape and Reel Packaging for 16 Pin SOIC Package



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CLARE LOCATIONS

Clare Headquarters
78 Cherry Hill Drive
Beverly, MA 01915
Tel: 1-978-524-6700
Fax: 1-978-524-4900
Toll Free: 1-800-27-CLARE

Clare Micronix Division
145 Columbia
Aliso Viejo, CA 92656-1490
Tel: 1-949-831-4622
Fax: 1-949-831-4628

SALES OFFICES

AMERICAS

Americas Headquarters

Clare
78 Cherry Hill Drive
Beverly, MA 01915
Tel: 1-978-524-6700
Fax: 1-978-524-4900
Toll Free: 1-800-27-CLARE

Eastern Region

Clare
P.O. Box 856
Mahwah, NJ 07430
Tel: 1-201-236-0101
Fax: 1-201-236-8685
Toll Free: 1-800-27-CLARE

Central Region

Clare Canada Ltd.
3425 Harvester Road, Suite 202
Burlington, Ontario L7N 3N1
Tel: 1-905-333-9066
Fax: 1-905-333-1824

Western Region

Clare
1852 West 11th Street, #348
Tracy, CA 95376
Tel: 1-209-832-4367
Fax: 1-209-832-4732
Toll Free: 1-800-27-CLARE

Canada

Clare Canada Ltd.
3425 Harvester Road, Suite 202
Burlington, Ontario L7N 3N1
Tel: 1-905-333-9066
Fax: 1-905-333-1824

EUROPE

European Headquarters

CP Clare nv
Bampslaan 17
B-3500 Hasselt (Belgium)
Tel: 32-11-300868
Fax: 32-11-300890

France

Clare France Sales
Lead Rep
99 route de Versailles
91160 Champlan
France
Tel: 33 1 69 79 93 50
Fax: 33 1 69 79 93 59

Germany

Clare Germany Sales
ActiveComp Electronic GmbH
Mitterstrasse 12
85077 Manching
Germany
Tel: 49 8459 3214 10
Fax: 49 8459 3214 29

Italy

C.L.A.R.E.s.a.s.
Via C. Colombo 10/A
I-20066 Melzo (Milano)
Tel: 39-02-95737160
Fax: 39-02-95738829

Sweden

Clare Sales
Comptronic AB
Box 167
S-16329 Spånga
Tel: 46-862-10370
Fax: 46-862-10371

United Kingdom

Clare UK Sales
Marco Polo House
Cook Way
Bindon Road
Taunton
UK-Somerset TA2 6BG
Tel: 44-1-823 352541
Fax: 44-1-823 352797

ASIA/PACIFIC

Asian Headquarters

Clare
Room N1016, Chia-Hsin, Bldg II,
10F, No. 96, Sec. 2
Chung Shan North Road
Taipei, Taiwan R.O.C.
Tel: 886-2-2523-6368
Fax: 886-2-2523-6369

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